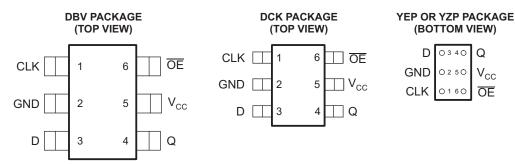


FEATURES

- Available in the Texas Instruments NanoStar[™] and NanoFree[™] Packages
- Supports 5-V V_{cc} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{nd} of 4 ns at 3.3 V
- Low Power Consumption, 10-µA Max Icc
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Partial-Power-Down Mode Operation

- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

This single D-type latch is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G374 features a 3-state output designed specifically for driving highly capacitive or relatively low-impedance loads. This device is particularly suitable for implementing buffer registers, input/output (I/O) ports, bidirectional bus drivers, and working registers.

NanoStar[™] and NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

On the positive transition of the clock (CLK) input, the Q output is set to the logic level set up at the data (D) input.

T _A	PACKAGE ⁽¹⁾		ORDERING PART NUMBER	TOP-SIDE MARKING ⁽²⁾ D4_ CA4 D4_		
	NanoStar – WCSP (DSBGA) 0.23-mm Large Bump – YEP	Deal of 2000	SN74LVC1G374YEPR	24		
	NanoFree – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	- Reel of 3000	SN74LVC1G374YZPR	U4		
40°C to 85°C		Reel of 3000	SN74LVC1G374DBVR	0.1.1		
	SOT (SOT-23) – DBV	Reel of 250	SN74LVC1G374DBVT	CA4		
		Reel of 3000	SN74LVC1G374DCKR	D4		
	SOT (SC-70) – DCK	Reel of 250	SN74LVC1G374DCKT			

ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site. YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition(1 = SnPb, • = Pb-free).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoStar, NanoFree are trademarks of Texas Instruments.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

A buffered output-enable (\overline{OE}) input can be used to place the output in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the output neither loads nor drives the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect the internal operations of the flip-flop. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

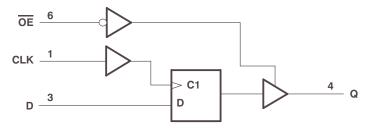
To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

	INPUTS		OUTPUT
OE	CLK	D	Q
L	\uparrow	L	L
L	\uparrow	Н	Н
L	H or L	Х	Q
Н	Х	Х	Z

FUNCTION TABLE

LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Voltage range applied to any output in the high-impedation	ance or power-off state ⁽²⁾	-0.5	6.5	V
Vo	Voltage range applied to any output in the high or low	state ⁽²⁾⁽³⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
		DBV package		165	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCK package		259	°C/W
		YEP/YZP package		123	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

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Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V	Supply voltage	Operating	1.65	5.5	V
V _{CC}	Supply voltage	Data retention only	1.5		v
		V _{CC} = 1.65 V to 1.95 V	$0.65 imes V_{CC}$		
\ <i>\</i>		V_{CC} = 2.3 V to 2.7 V	1.7		V
VIH	High-level input voltage	$V_{CC} = 3 V$ to 3.6 V	2		v
		V_{CC} = 4.5 V to 5.5 V	$0.7 imes V_{CC}$		
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	
		V_{CC} = 2.3 V to 2.7 V		0.7	V
V _{IL}	Low-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$		0.8	v
		V_{CC} = 4.5 V to 5.5 V		$0.3 \times V_{CC}$	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 1.65 V		-4	
		$V_{CC} = 2.3 V$		-8	
юн	High-level output current	N 2 N		-16	mA
		$V_{CC} = 3 V$		-24	
		$V_{CC} = 4.5 V$		-32	
		V _{CC} = 1.65 V		4	
		$V_{CC} = 2.3 V$		8	
OL	Low-level output current	N 2 N		16	mA
		$V_{CC} = 3 V$		24	
		$V_{CC} = 4.5 V$		32	
		V_{CC} = 1.8 V \pm 0.15 V, 2.5 V \pm 0.2 V		20	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
	-	V_{CC} = 5 V ± 0.5 V		5	
Γ _A	Operating free-air temperature		-40	85	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP ⁽¹⁾ MAX	UNIT
	I _{OH} = -100 μA	1.65 V to 5.5 V	V _{CC} – 0.1	
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2	
V	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9	v
V _{OH}	$I_{OH} = -16 \text{ mA}$	3 V	2.4	v
	$I_{OH} = -24 \text{ mA}$	3 V	2.3	
	$I_{OH} = -32 \text{ mA}$	4.5 V	3.8	
	I _{OL} = 100 μA	1.65 V to 5.5 V	0.1	
	I _{OL} = 4 mA	1.65 V	0.45	
V	I _{OL} = 8 mA	2.3 V	0.3	v
V _{OL}	I _{OL} = 16 mA	3 V	0.4	
	I _{OL} = 24 mA	5 V	0.55	5
	I _{OL} = 32 mA	4.5 V	0.55	;
I _I	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V	±1	μA
I _{OZ}	$V_0 = 0$ to 5.5 V		±5	μA
I _{off}	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0	±10	μA
I _{CC}	$V_1 = 5.5 \text{ V or GND}, \qquad I_0 = 0$	1.65 V to 5.5 V	10	μA
ΔI_{CC}	One input at $V_{CC} - 0.6 V$, Other inputs at V_{CC} or GND	3 V to 5.5 V	500	μA
C _i	$V_1 = V_{CC}$ or GND	3.3 V	3	pF
Co	$V_{O} = V_{CC}$ or GND	3.3 V	6	pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			V _{CC} = 1.8 V ± 0.15 V		2.5 V V	V _{CC} = 3 ± 0.3		V _{CC} = ± 0.5		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{clock}	Clock frequency		100		125		150		175	MHz
t _w	Pulse duration, CLK high or low	3.3		3		2.8		2.5		ns
t _{su}	Setup time, data before CLK \uparrow	3.5		2.5		2		1.5		ns
t _h	Hold time, data after CLK \uparrow	3.4		1.6		1.5		1.5		ns

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM INPUT	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = ± 0.2		V _{CC} = ± 0.3	3.3 V 3 V	= V _{CC} ± 0.5	= 5 V 5 V	UNIT
	INFUT	(001901)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	ĺ
f _{max}			100		125		150		175		MHz
t _{pd}	CLK	Q	2.5	15	2	6	1.4	4	1	3	ns
t _{en}	ŌĒ	Q	2.2	12	2	4.8	1.3	3.8	1.1	2.5	ns
t _{dis}	ŌĒ	Q	2.2	11	2	4.8	1.6	4.5	1.2	3.1	ns

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Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 2)

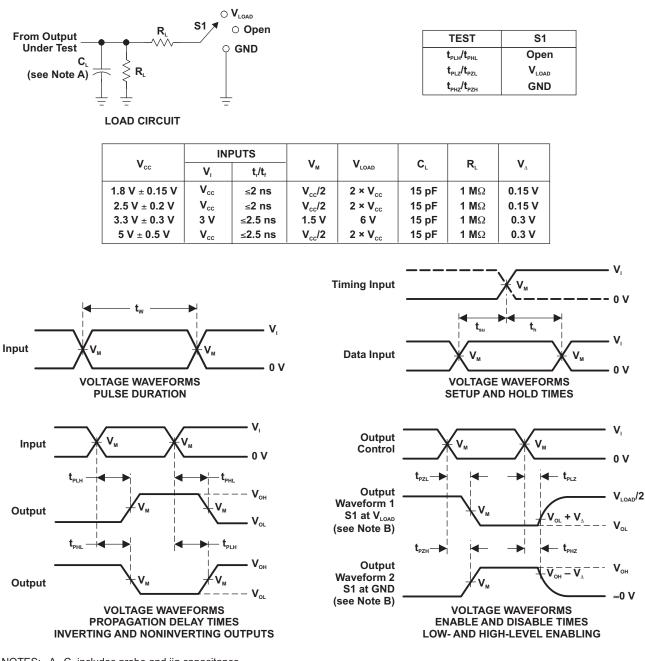
PARAMETER	FROM INPUT	TO (OUTPUT)	V _{CC} = ± 0.1		V_{CC} = 2.5 V \pm 0.2 V		V_{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
	INFUT	(001201)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			100		125		150		175		MHz
t _{pd}	CLK	Q	2.7	18.3	1.8	8.2	1.6	6	1	4	ns
t _{en}	ŌĒ	Q	2	13	1.5	6.3	0.9	5	0.7	3.5	ns
t _{dis}	ŌĒ	Q	2	14	1.1	5.3	1.4	4.5	0.8	3.1	ns

Operating Characteristics

 $T_A = 25^{\circ}C$

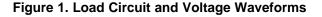
	PARAMETER		TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	V _{CC} = 5 V TYP	UNIT
<u> </u>	Power dissipation	Outputs enabled	f = 10 MHz	24	24	25	27	рF
Cpd	capacitance	Outputs disabled		8	8	9	11	рг

PARAMETER MEASUREMENT INFORMATION



NOTES: A. $C_{\scriptscriptstyle L}$ includes probe and jig capacitance.

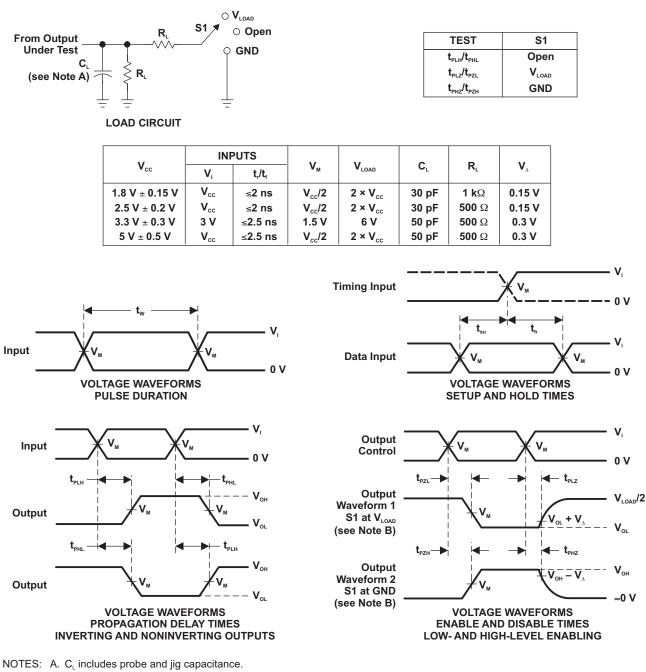
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_o = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and \dot{t}_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{od} .
- H. All parameters and waveforms are not applicable to all devices.





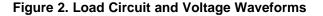
SCES520B-DECEMBER 2003-REVISED SEPTEMBER 2006

PARAMETER MEASUREMENT INFORMATION (continued)



 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.

- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{od} .
- H. All parameters and waveforms are not applicable to all devices.





11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
74LVC1G374DBVRE4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CA45 ~ CA4R)	Samples
74LVC1G374DBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CA45 ~ CA4R)	Samples
74LVC1G374DCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(D45 ~ D4R)	Samples
74LVC1G374DCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(D45 ~ D4R)	Samples
SN74LVC1G374DBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CA45 ~ CA4R)	Samples
SN74LVC1G374DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(D45 ~ D4R)	Samples
SN74LVC1G374YZPR	ACTIVE	DSBGA	YZP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(D47 ~ D4N)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.



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11-Apr-2013

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OTHER QUALIFIED VERSIONS OF SN74LVC1G374 :

Automotive: SN74LVC1G374-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G374DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G374DBVR	SOT-23	DBV	6	3000	178.0	9.2	3.3	3.2	1.55	4.0	8.0	Q3
SN74LVC1G374DCKR	SC70	DCK	6	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G374YZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

13-Oct-2012

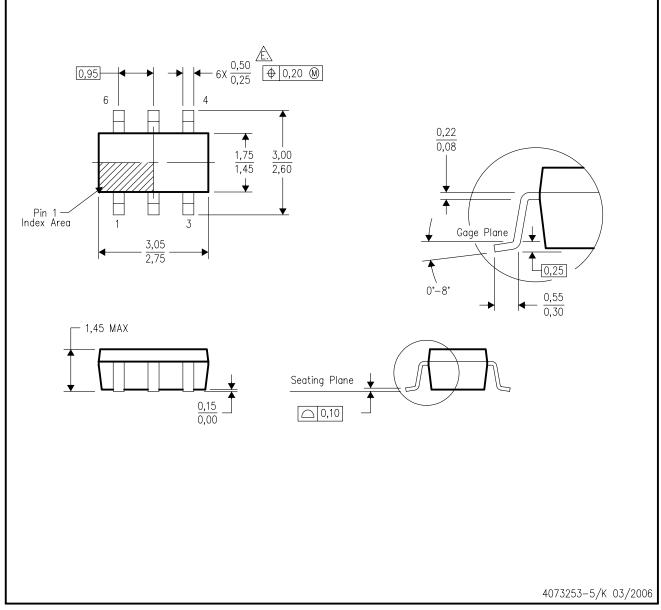


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G374DBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
SN74LVC1G374DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
SN74LVC1G374DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74LVC1G374YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0

DBV (R-PDSO-G6)

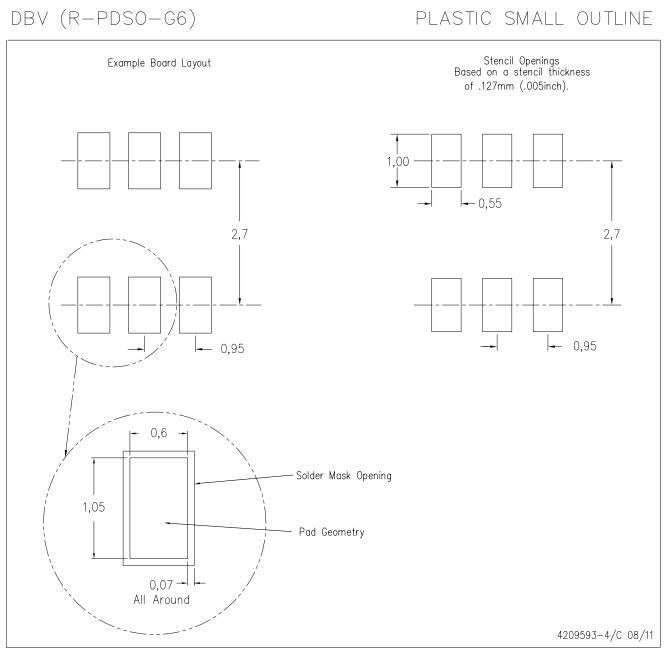
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- È. Falls within JEDEC MO-178 Variation AB, except minimum lead width.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AB.



LAND PATTERN DATA



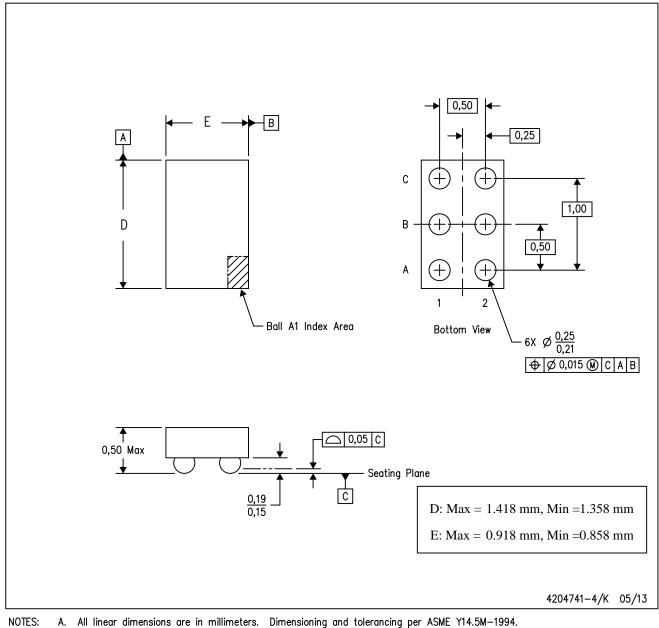
NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



YZP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



- Α.
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

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